



SLPS408-JANUARY 2013 www.ti.com

N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD58887Q3

FEATURES

- **Optimized for 5V Gate Drive**
- Resistance Rated at V_{GS} = 2.5V
- Ultra Low Qg and Qgd
- **Low Thermal Resistance**
- **Avalanche Rated**
- Pb Free Terminal Plating
- **RoHS Compliant**
- **Halogen Free**
- SON 3.3mm x 3.3mm Plastic Package

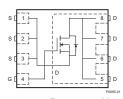
APPLICATIONS

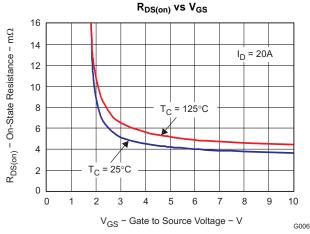
- **Point-of-Load Synchronous Buck Converter** for Applications in Networking, Telecom and **Computing Systems**
- **Optimized for Control or Synchronous FET Applications**

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion and optimized for 5V gate drive applications.

Figure 1. Top View





PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	25	V	
Q_g	Gate Charge Total (4.5V)	6.5	nC	
Q_{gd}	Gate Charge Gate to Drain	1.2	nC	
		$V_{GS} = 2.5V$	6.1	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V	4.3	mΩ
25(0.1)		$V_{GS} = 8V$	3.8	mΩ
V_{th}	Threshold Voltage	0.85		V

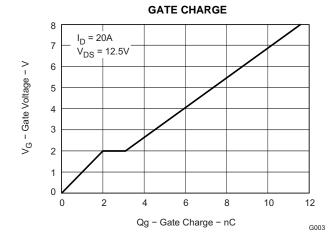
ORDERING INFORMATION

Device	Device Package		Package Media Qty	
CSD58887Q3	SON 3.3 × 3.3 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	٧
V_{GS}	Gate to Source Voltage	+10 / -8	٧
	Continuous Drain Current, T _C = 25°C	60	Α
I _D	Continuous Drain Current ⁽¹⁾	21	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	115	Α
P_D	Power Dissipation ⁽¹⁾	3	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 40A, L = 0.1 mH, R_G = 25\Omega$	80	mJ

- (1) Typical $R_{\theta JA} = 39^{\circ}C/W$ on $1in^2$ Cu (2 oz.) on 0.060" thick FR4 PCB.
- (2) Pulse width ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Ch	naracteristics					
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = 250\mu A$	25			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 20V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	0.6	0.85	1.1	V
		$V_{GS} = 2.5V, I_{DS} = 20A$		6.1	7.8	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V, I_{DS} = 20A$		4.3	5.5	mΩ
		V _{GS} = 8V, I _{DS} = 20A		3.8	4.5	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 20A		121		S
Dynamic	: Characteristics		*		*	
C _{ISS}	Input Capacitance			1050	1350	pF
Coss	Output Capacitance	V _{GS} = 0V, V _{DS} = 12.5V, f = 1MHz		730	950	pF
C _{RSS}	Reverse Transfer Capacitance			53	69	pF
R _g	Series Gate Resistance			1.5	3	Ω
Qg	Gate Charge Total (4.5V)			6.5	9.2	nC
Q _{gd}	Gate Charge Gate to Drain	V 40 5V 1 00A		1.2		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 12.5V, I_{D} = 20A$		2.1		nC
Qg(th)	Gate Charge at Vth			1		nC
Q _{OSS}	Output Charge	$V_{DS} = 13V, V_{GS} = 0V$		15		nC
t _{d(on)}	Turn On Delay Time			4.8		ns
t _r	Rise Time	$V_{DS} = 12.5V, V_{GS} = 4.5V I_{D} = 20A$		16.1		ns
t _{d(off)}	Turn Off Delay Time	$R_G = 2\Omega$		13.8		ns
t _f	Fall Time		5.2			ns
Diode Cl	haracteristics		•			
V _{SD}	Diode Forward Voltage	I _S = 20A, V _{GS} = 0V		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V 40V I 00A 4V/4 000A		14.5		nC
t _{rr}	Reverse Recovery Time	$V_{DD} = 13V$, $I_F = 20A$, $di/dt = 300A/\mu s$		20		ns

THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

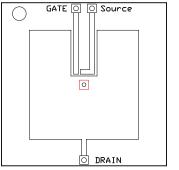
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.4	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (1)(2)			58	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

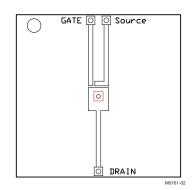
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Max $R_{\theta JA} = 58^{\circ}C/W$ when mounted on 1 inch² of 2 oz. Cu.



Max $R_{\theta JA} = 162^{\circ}C/W$ when mounted on minimum pad area of 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

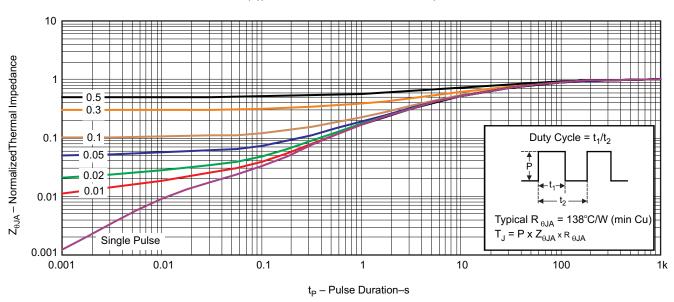


Figure 2. Transient Thermal Impedance

G012

TEXAS INSTRUMENTS

TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

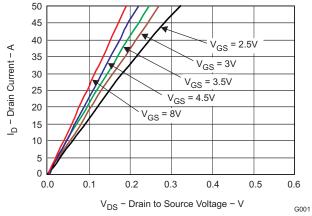


Figure 3. Saturation Characteristics

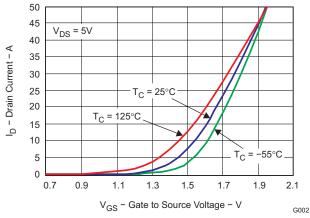


Figure 4. Transfer Characteristics

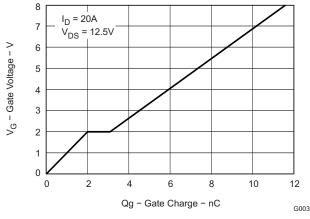


Figure 5. Gate Charge

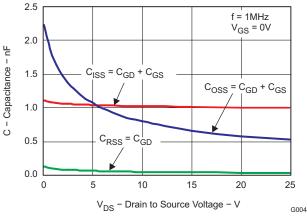


Figure 6. Capacitance

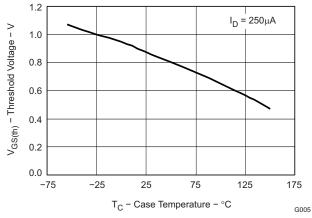


Figure 7. Threshold Voltage vs. Temperature

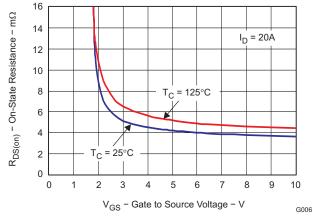


Figure 8. On Resistance vs. Gate Voltage

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

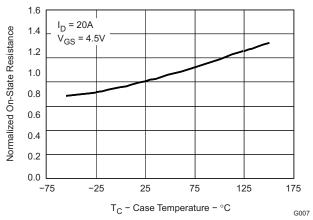


Figure 9. Normalized On Resistance vs. Temperature

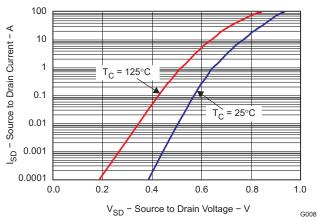


Figure 10. Typical Diode Forward Voltage

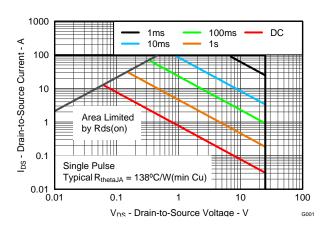


Figure 11. Maximum Safe Operating Area

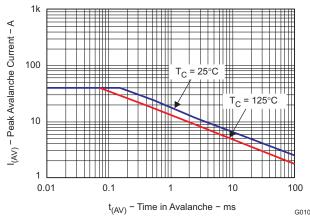


Figure 12. Single Pulse Unclamped Inductive Switching

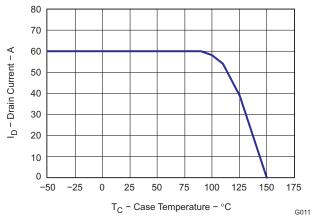


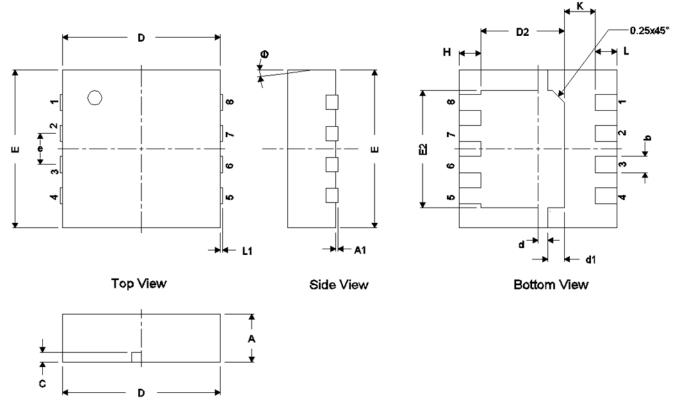
Figure 13. Maximum Drain Current vs. Temperature

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MECHANICAL DATA

Q3 Package Dimensions



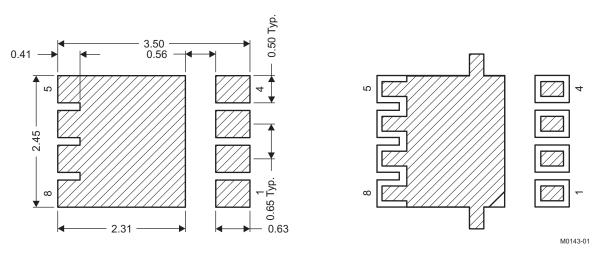
Front View

DIM	I	MILLIMETERS	;		INCHES	
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
С	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
d	0.150	0.200	0.250	0.006	0.008	0.010
D2	1.650	1.750	1.800	0.065	0.069	0.071
d1	0.300	0.350	0.400	0.012	0.014	0.016
Е	3.200	3.300	3.400	0.126	0.130	0.134
E2	2.350	2.450	2.550	0.093	0.096	0.100
е		0.650 TYP			0.026 TYP	
Н	0.350	0.450	0.550	0.014	0.018	0.022
K		0.650 TYP			0.26 TYP	
L	0.350	0.450	0.550	0.014	0.018	0.022
L1	0	-	0	0	_	0
θ	0	-	0	0	_	0

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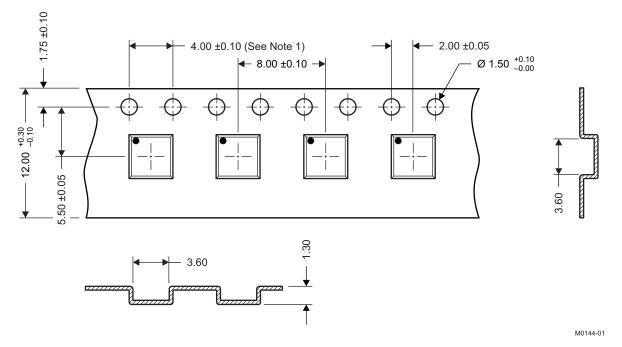
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Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q3 Tape and Reel Information



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

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PACKAGE OPTION ADDENDUM

21-Mar-2013

PACKAGING INFORMATION

Orderable Device		Package Type	Package Drawing		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Diawing			(2)		(3)		(4)	
CSD58887Q3	PREVIEW	SON	DQG	8		Pb-Free (RoHS	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD58887	
						Exempt)					

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

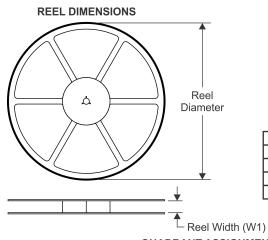
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PACKAGE MATERIALS INFORMATION

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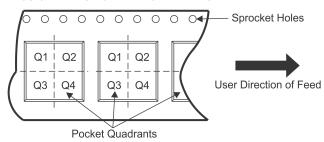
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

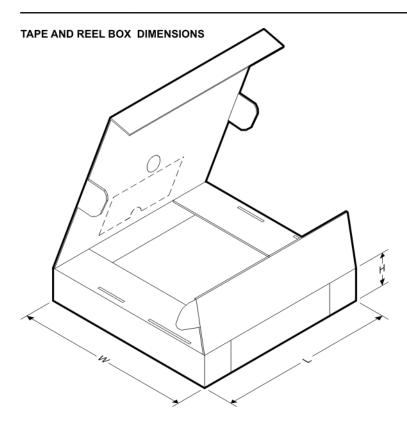


*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD58887Q3	SON	DQG	8	0	330.0	12.8	3.6	3.6	1.2	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD58887Q3	SON	DQG	8	0	335.0	335.0	32.0

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